

TLP292

1. Applications

- Switching Power Supplies
- Programmable Logic Controllers (PLCs)
- I/O Interface Boards

2. General

TLP292 is a high isolation and a low AC input type photocoupler that consists of phototransistor optically coupled to two antiparallel InGaAs infrared emitting diodes in a SO4 package.

Since TLP292 is guaranteed high isolation voltage (3750 Vrms) and wide operating temperature range ($T_a = -55$ to 125°C), it is suitable for high density surface mounting applications such as small type switching power supplies and programmable controllers.

3. Features

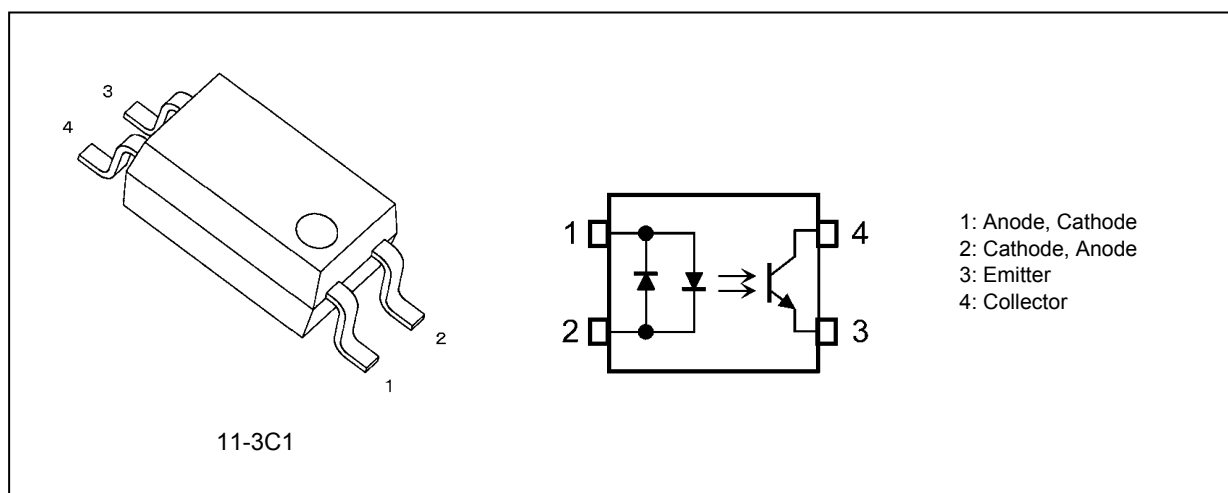
- (1) Collector-emitter voltage: 80 V (min)
- (2) Current transfer ratio: 50 % (min) (@ $I_F = \pm 0.5$ mA, $V_{CE} = 5$ V)
GB Rank: 100 % (min) (@ $I_F = \pm 0.5$ mA, $V_{CE} = 5$ V)
- (3) Isolation voltage: 3750 Vrms (min)
- (4) Operating temperature range: -55 to 125°C
- (5) Safety standards
UL-approved: UL1577, File No.E67349
cUL-approved: CSA Component Acceptance Service No.5A File No.E67349
VDE-approved: EN60747-5-5, EN60065 or EN60950-1 (**Note 1**)
: EN62368-1 (Pending) (**Note 1**)
CQC-approved: GB4943.1, GB8898 Thailand Factory



仅适用于海拔 2000m 以下地区安全使用

Note 1: When a VDE approved type is needed, please designate the **Option (V4)**.

4. Packaging and Pin Assignment



Start of commercial production
2013-09

5. Mechanical Parameters

Characteristics	Min	Unit
Creepage distances	5.0	mm
Clearance	5.0	
Internal isolation thickness	0.4	

6. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25\text{ }^{\circ}\text{C}$)

	Characteristics	Symbol	Note	Rating	Unit
LED	R.M.S. forward current	$I_{F(RMS)}$		± 50	mA
	Input forward current derating ($T_a \geq 90\text{ }^{\circ}\text{C}$)	$\Delta I_F / \Delta T_a$		-1.5	mA/ $^{\circ}\text{C}$
	Input forward current (pulsed)	I_{FP}	(Note 1)	± 1	A
	Input power dissipation	P_D		100	mW
	Input power dissipation derating ($T_a \geq 90\text{ }^{\circ}\text{C}$)	$\Delta P_D / \Delta T_a$		-2.9	mW/ $^{\circ}\text{C}$
	Junction temperature	T_j		135	$^{\circ}\text{C}$
Detector	Collector-emitter voltage	V_{CEO}		80	V
	Emitter-collector voltage	V_{ECO}		7	V
	Collector current	I_C		50	mA
	Collector power dissipation	P_C		150	mW
	Collector power dissipation derating ($T_a \geq 25\text{ }^{\circ}\text{C}$)	$\Delta P_C / \Delta T_a$		-1.5	mW/ $^{\circ}\text{C}$
	Junction temperature	T_j		135	$^{\circ}\text{C}$
Common	Operating temperature	T_{opr}		-55 to 125	$^{\circ}\text{C}$
	Storage temperature	T_{stg}		-55 to 125	$^{\circ}\text{C}$
	Lead soldering temperature (10 s)	T_{sol}		260	$^{\circ}\text{C}$
	Total power dissipation	P_T		200	mW
	Total power dissipation derating ($T_a \geq 25\text{ }^{\circ}\text{C}$)	$\Delta P_T / \Delta T_a$		-2.0	mW/ $^{\circ}\text{C}$
	Isolation voltage AC, 60 s, R.H. $\leq 60\%$	BV_S	(Note 2)	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: Pulse width (PW) $\leq 0.1\text{ ms}$, $f = 100\text{ Hz}$

Note 2: This device is considered as a two-terminal device: Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together.

7. Electrical Characteristics (Unless otherwise specified, $T_a = 25\text{ }^{\circ}\text{C}$)

	Characteristics	Symbol	Note	Test Condition	Min	Typ.	Max	Unit
LED	Input forward voltage	V_F		$I_F = \pm 10\text{ mA}$	1.1	1.25	1.4	V
	Input capacitance	C_t		$V = 0\text{ V}$, $f = 1\text{ MHz}$	—	60	—	pF
Detector	Collector-emitter breakdown voltage	$V_{(BR)CEO}$		$I_C = 0.5\text{ mA}$	80	—	—	V
	Emitter-collector breakdown voltage	$V_{(BR)ECO}$		$I_E = 0.1\text{ mA}$	7	—	—	V
	Dark Current	I_{DARK}		$V_{CE} = 48\text{ V}$	—	0.01	0.08	μA
				$V_{CE} = 48\text{ V}$, $T_a = 85\text{ }^{\circ}\text{C}$	—	2	50	μA
	Collector-emitter capacitance	C_{CE}		$V = 0\text{ V}$, $f = 1\text{ MHz}$	—	10	—	pF

8. Coupled Electrical Characteristics (Unless otherwise specified, $T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Note	Test Condition	Min	Typ.	Max	Unit
Current transfer ratio	I_C/I_F	(Note 1)	$I_F = \pm 5\text{ mA}, V_{CE} = 5\text{ V}$	50	—	600	%
			$I_F = \pm 5\text{ mA}, V_{CE} = 5\text{ V}, \text{Rank GB}$	100	—	600	
			$I_F = \pm 0.5\text{ mA}, V_{CE} = 5\text{ V}$	50	—	600	
			$I_F = \pm 0.5\text{ mA}, V_{CE} = 5\text{ V}, \text{Rank GB}$	100	—	600	
Saturated current transfer ratio	$I_C/I_{F(\text{sat})}$		$I_F = \pm 1\text{ mA}, V_{CE} = 0.4\text{ V}$	—	60	—	
			$I_F = \pm 1\text{ mA}, V_{CE} = 0.4\text{ V}, \text{Rank GB}$	30	—	—	
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$		$I_C = 2.4\text{ mA}, I_F = \pm 8\text{ mA}$	—	—	0.3	V
			$I_C = 0.2\text{ mA}, I_F = \pm 1\text{ mA}$	—	0.2	—	
			$I_C = 0.2\text{ mA}, I_F = \pm 1\text{ mA}, \text{Rank GB}$	—	—	0.3	
OFF-state collector current	$I_{C(\text{off})}$		$V_F = \pm 0.7\text{ V}, V_{CE} = 48\text{ V}$	—	1	10	μA
Collector current ratio	$I_C(\text{ratio})$		See Fig. 8.1 $I_C(I_F = -5\text{ mA}) / I_C(I_F = 5\text{ mA})$	0.33	—	3	—

Note 1: See Table 8.1 for current transfer ratio.

Table 8.1 Current Transfer Ratio (CTR) Rank (Note) (Unless otherwise specified, $T_a = 25^\circ\text{C}$)

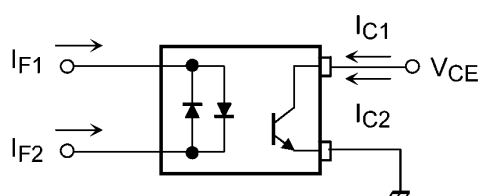
Rank	Rank short code	Note	Test Condition	Current transfer ratio I_C/I_F (min)	Current transfer ratio I_C/I_F (max)	Marking of classification	Unit
Blank	—		$I_F = \pm 5\text{ mA}, V_{CE} = 5\text{ V}$	50	600	Blank, YE, GR, GB, BL	%
			$I_F = \pm 0.5\text{ mA}, V_{CE} = 5\text{ V}$				
Y	—		$I_F = \pm 5\text{ mA}, V_{CE} = 5\text{ V}$	50	150	YE	
			$I_F = \pm 0.5\text{ mA}, V_{CE} = 5\text{ V}$				
GR	—		$I_F = \pm 5\text{ mA}, V_{CE} = 5\text{ V}$	100	300	GR	
			$I_F = \pm 0.5\text{ mA}, V_{CE} = 5\text{ V}$				
GB	—		$I_F = \pm 5\text{ mA}, V_{CE} = 5\text{ V}$	100	600	GB, GR, BL	
			$I_F = \pm 0.5\text{ mA}, V_{CE} = 5\text{ V}$				
BL	—		$I_F = \pm 5\text{ mA}, V_{CE} = 5\text{ V}$	200	600	BL	
			$I_F = \pm 0.5\text{ mA}, V_{CE} = 5\text{ V}$				

Note: Specify both the part number and a rank in this format when ordering.

Example: TLP292(GB,E)

For safety standard certification, however, specify the part number alone.

Example: TLP292(GB,E → TLP292



$$I_C(\text{ratio}) = \frac{I_{C2}(I_F = I_{F2}, V_{CE} = 5\text{ V})}{I_{C1}(I_F = I_{F1}, V_{CE} = 5\text{ V})}$$

Fig. 8.1 Collector Current Ratio Test Circuit

9. Isolation Characteristics (Unless otherwise specified, $T_a = 25\text{ }^{\circ}\text{C}$)

Characteristics	Symbol	Note	Test Condition	Min	Typ.	Max	Unit
Total capacitance (input to output)	C_S	(Note 1)	$V_S = 0\text{ V}$, $f = 1\text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	(Note 1)	$V_S = 500\text{ V}$, R.H. $\leq 60\%$	1×10^{12}	10^{14}	—	Ω
Isolation voltage	BV_S	(Note 1)	AC, 60 s	3750	—	—	V_{rms}
			AC, 1 s in oil	—	10000	—	
			DC, 60 s in oil	—	10000	—	Vdc

Note 1: This device is considered as a two-terminal device: Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together.

10. Switching Characteristics (Unless otherwise specified, $T_a = 25\text{ }^{\circ}\text{C}$)

Characteristics	Symbol	Note	Test Condition	Min	Typ.	Max	Unit
Rise time	t_r		$V_{CC} = 10\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\text{ }\Omega$	—	2	—	μs
Fall time	t_f			—	3	—	
Turn-on time	t_{on}			—	3	—	
Turn-off time	t_{off}			—	3	—	
Turn-on time	t_{on}		See Fig. 10.1 $R_L = 1.9\text{ k}\Omega$, $V_{CC} = 5\text{ V}$, $I_F = \pm 16\text{ mA}$	—	1.3	—	
Storage time	t_s			—	20	—	
Turn-off time	t_{off}			—	35	—	
Turn-on time	t_{on}		See Fig. 10.1 $R_L = 4.7\text{ k}\Omega$, $V_{CC} = 5\text{ V}$, $I_F = \pm 1.6\text{ mA}$	—	4	—	
Storage time	t_s			—	7	—	
Turn-off time	t_{off}			—	30	—	

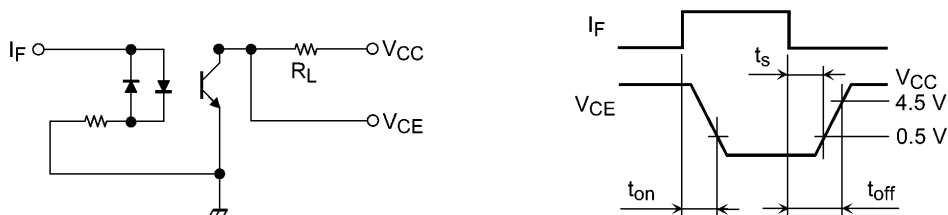


Fig. 10.1 Switching Time Test Circuit and Waveform

11. Characteristics Curves (Note)

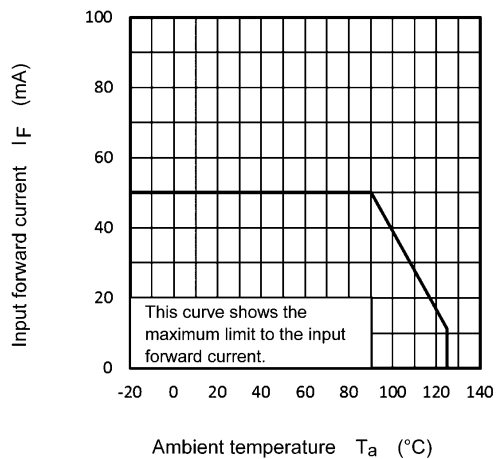


Fig. 11.1 $I_F - T_a$

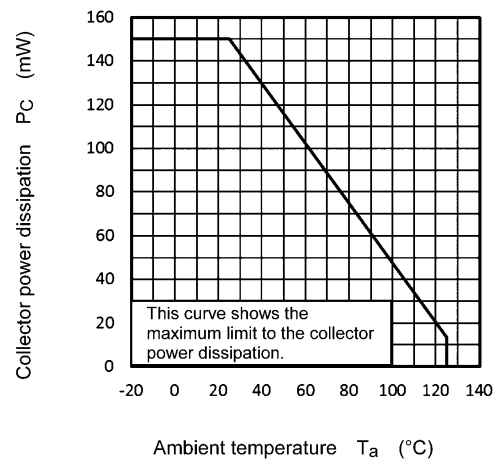


Fig. 11.2 $P_C - T_a$

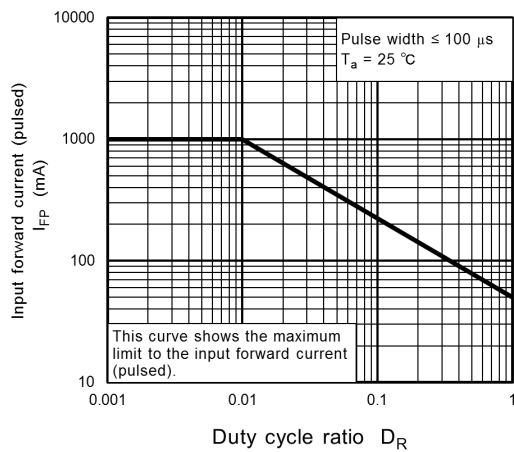


Fig. 11.3 $I_{FP} - D_R$

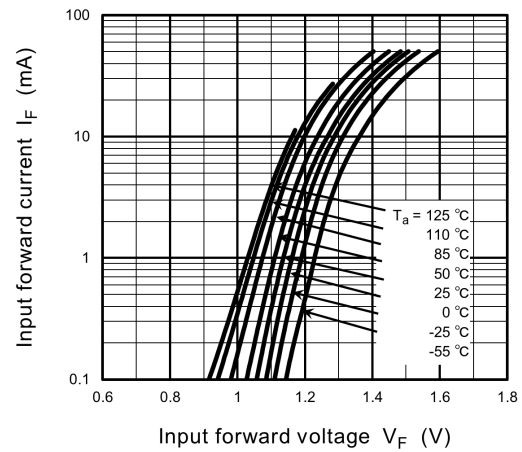


Fig. 11.4 $I_F - V_F$

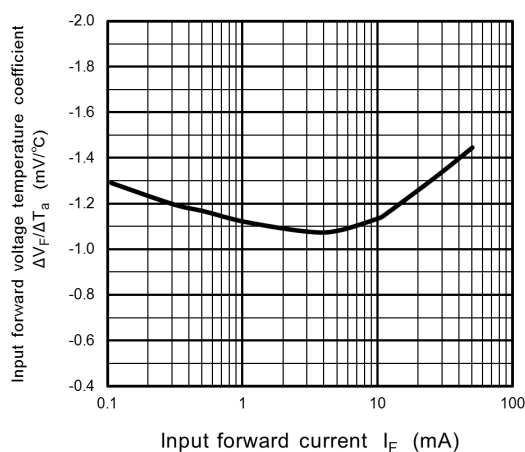


Fig. 11.5 $\Delta V_F / \Delta T_a - I_F$

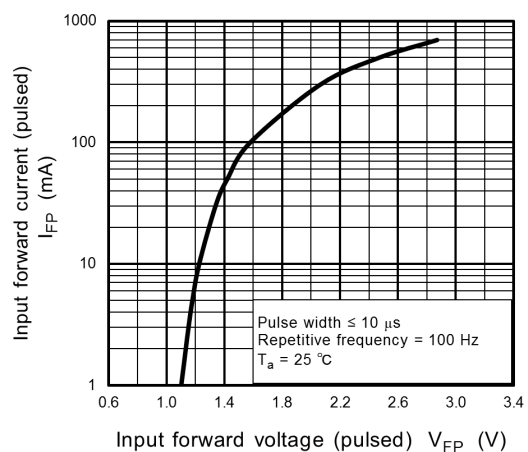


Fig. 11.6 $I_{FP} - V_{FP}$

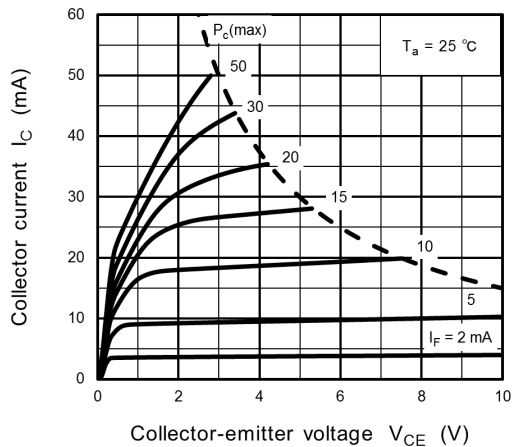


Fig. 11.7 $I_C - V_{CE}$

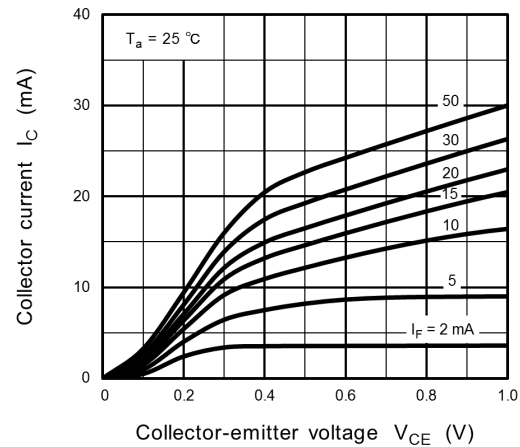


Fig. 11.8 $I_C - V_{CE}$

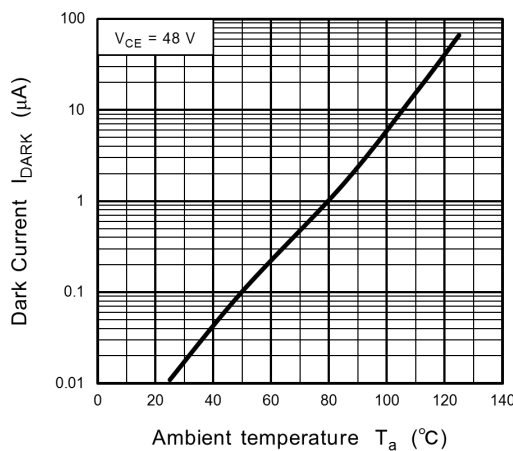


Fig. 11.9 $I_{DARK} - T_a$

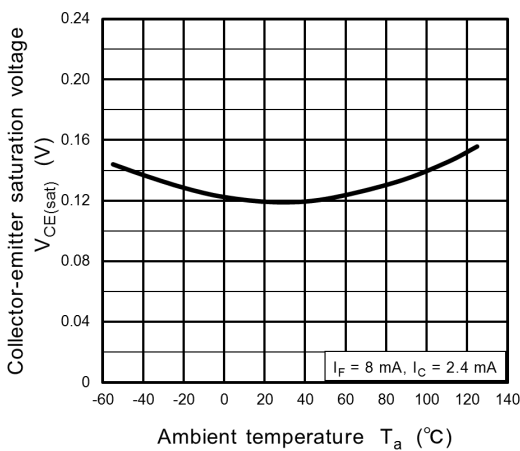


Fig. 11.10 $V_{CE(sat)} - T_a$

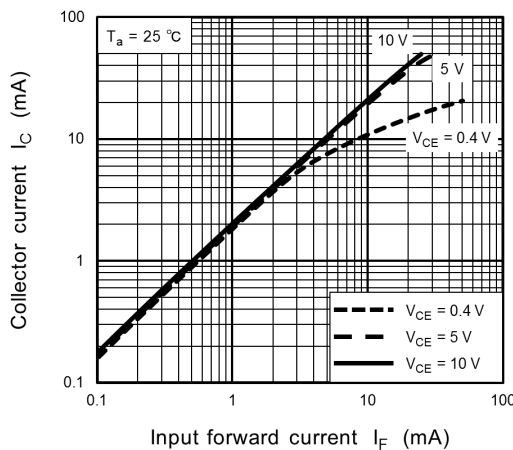


Fig. 11.11 $I_C - I_F$

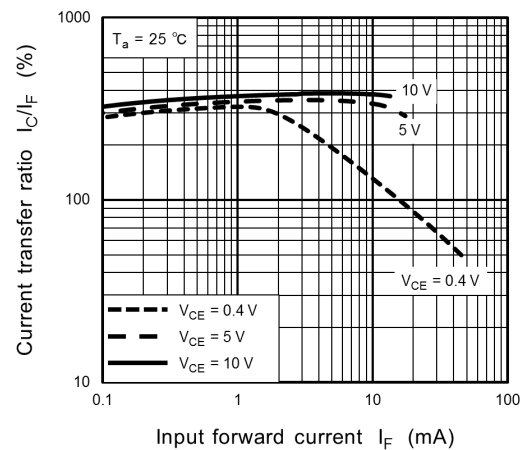


Fig. 11.12 $I_C/I_F - I_F$

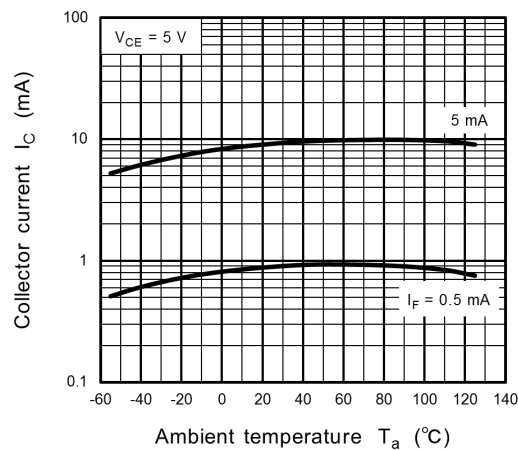


Fig. 11.13 $I_C - T_a$

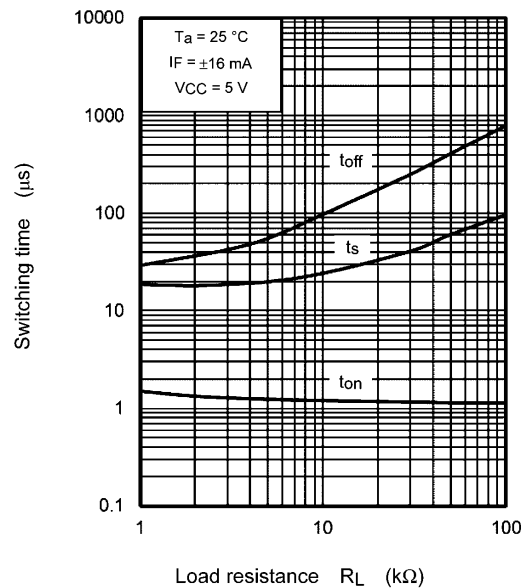


Fig. 11.14 Switching Time - R_L

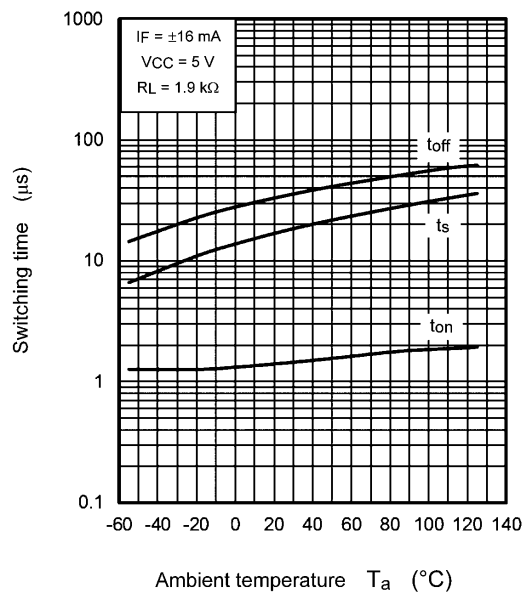


Fig. 11.15 Switching Time - T_a

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

12. Soldering and Storage

12.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

- When using soldering reflow.

The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

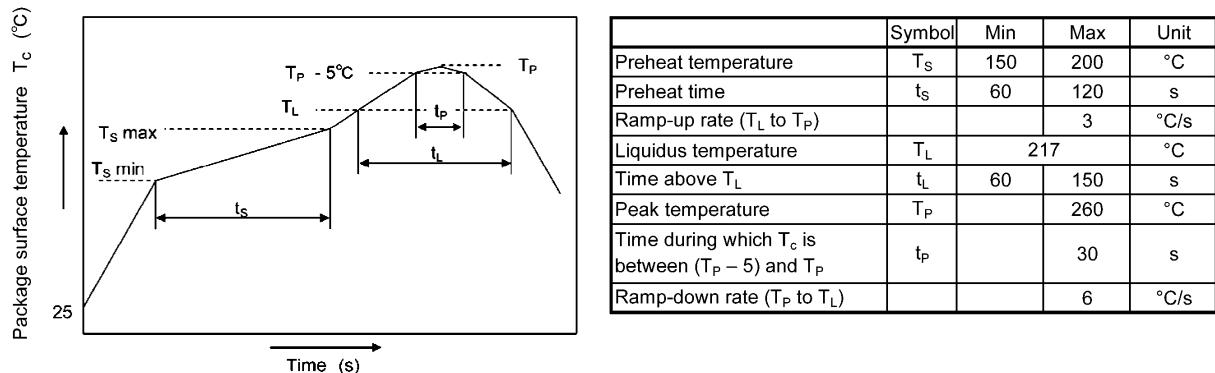


Fig. 12.1.1 An Example of a Temperature Profile When Lead(Pb)-Free Solder Is Used

- When using soldering flow

Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds.

Mounting condition of 260 °C within 10 seconds is recommended.

Flow soldering must be performed once.

- When using soldering Iron

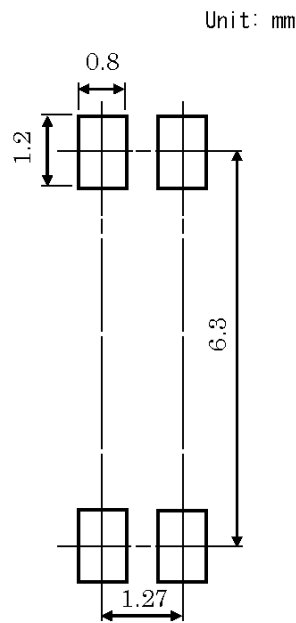
Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C

Heating by soldering iron must be done only once per lead.

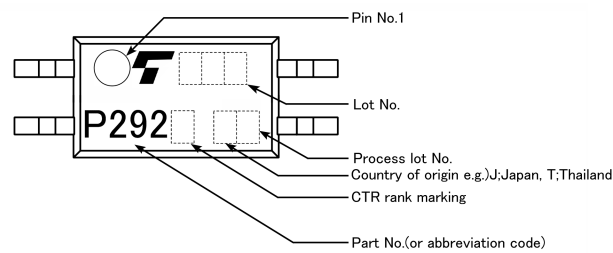
12.2. Precautions for General Storage

- Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5 °C to 35 °C and 45 % to 75 %, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- When restoring devices after removal from their packing, use anti-static containers.
- Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

13. Land Pattern Dimensions (for reference only)



14. Marking



15. EN60747-5-5 Option (V4) Specification

- Part number: TLP292 (**Note 1**)
- The following part naming conventions are used for the devices that have been qualified according to option (V4) of EN60747.

Example: TLP292(V4GR-TL,E(T

V4: EN60747 option

GR: CTR rank

TL: Tape type (L direction: TPL)

E: [[G]]/RoHS COMPATIBLE (**Note 2**)

T: Domestic ID (Country/Region of origin: Thailand)

Note 1: Use TOSHIBA standard type number for safety standard application.

e.g., TLP292(V4GR-TL,E(T → TLP292

Note 2: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Description	Symbol	Rating	Unit
Application classification			
for rated mains voltage ≤ 150 Vrms		I-IV	—
for rated mains voltage ≤ 300 Vrms		I-III	
Climatic classification		55 / 125 / 21	—
Pollution degree		2	—
Maximum operating insulation voltage	VIORM	707	Vpeak
Input to output test voltage, Method A Vpr = $1.6 \times VIORM$, type and sample test tp = 10 s, partial discharge < 5 pC	Vpr	1131	Vpeak
Input to output test voltage, Method B Vpr = $1.875 \times VIORM$, 100 % production test tp = 1 s, partial discharge < 5 pC	Vpr	1330	Vpeak
Highest permissible overvoltage (transient overvoltage, tpr = 60 s)	VTR	6000	Vpeak
Safety limiting values (max. permissible ratings in case of fault, also refer to thermal derating curve)			
current (input current IF, Pso = 0)	Isi	250	mA
power (output or total power dissipation)	Pso	400	mW
temperature	Ts	150	°C
Insulation resistance VIO = 500 V, Ta = 25 °C VIO = 500 V, Ta = 100 °C VIO = 500 V, Ta = Ts	Rsi	$\geq 10^{12}$ $\geq 10^{11}$ $\geq 10^9$	Ω

Fig. 15.1 EN60747 Insulation Characteristics

Table 15.1 Insulation Related Specifications (Note)

Insulation Related Parameters	Symbol	TLP292
Minimum creepage distance	Cr	5.0 mm
Minimum clearance	Cl	5.0 mm
Minimum insulation thickness	ti	0.4 mm
Comparative tracking index	CTI	175

Note: This photocoupler is suitable for **safe electrical isolation** only within the safety limit data.
Maintenance of the safety data shall be ensured by means of protective circuits.



Fig. 15.2 Marking on packing for EN60747

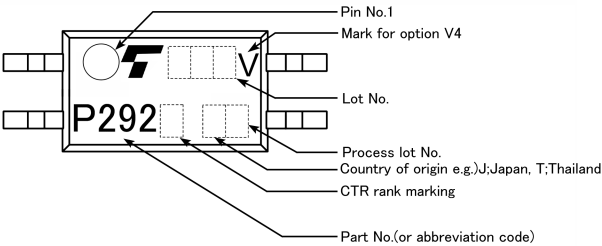


Fig. 15.3 Marking Example (Note)

Note: The above marking is applied to the photocouplers that have been qualified according to option (V4) of EN60747.

Figure 1 Partial discharge measurement procedure according to EN60747
Destructive test for qualification and sampling tests.

Method A

(for type and sampling tests,
destructive tests)

t_1, t_2	= 1 to 10 s
t_3, t_4	= 1 s
t_p (Measuring time for partial discharge)	= 10 s
t_b	= 12 s
t_{ini}	= 60 s

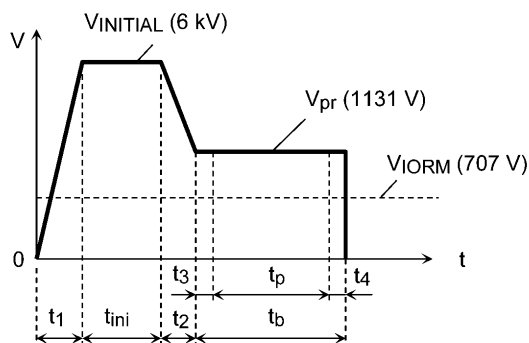


Figure 2 Partial discharge measurement procedure according to EN60747
Non-destructive test for 100 % inspection.

Method B

(for sample test, non-
destructive test)

t_3, t_4	= 0.1 s
t_p (Measuring time for partial discharge)	= 1 s
t_b	= 1.2 s

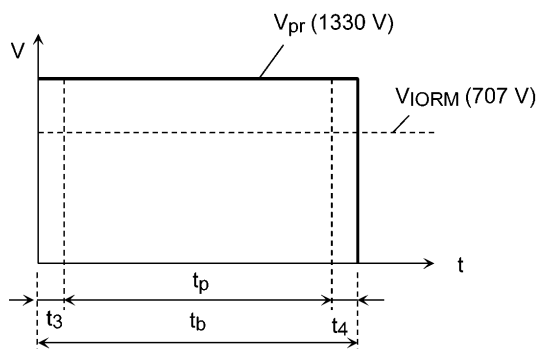


Figure 3 Dependency of maximum safety ratings on ambient temperature

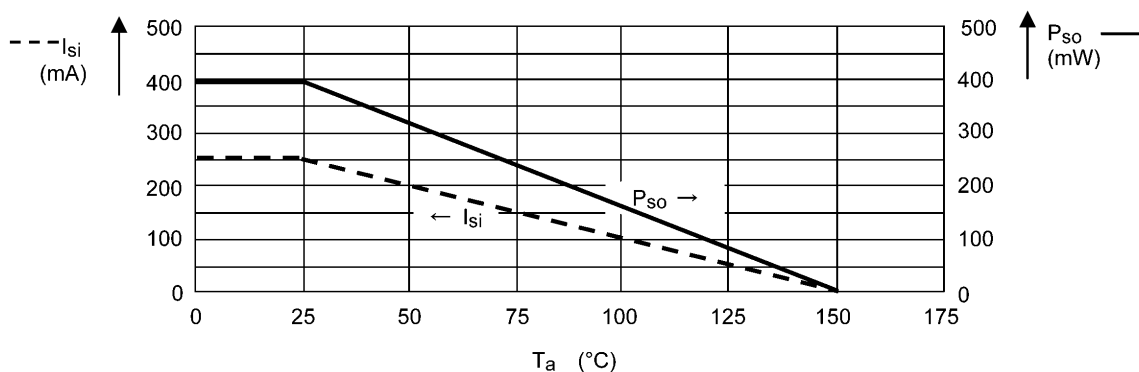


Fig. 15.4 Measurement Procedure

16. Embossed-Tape Packing (TPL), (TPR) Specification for Mini-Flat Photocouplers

16.1. Applicable Package

Package Name	Product Type
SO4	Mini flat coupler

16.2. Product Naming Conventions

Type of package used for shipment is denoted by a symbol suffix after a part number. The method of classification is as below.

Example) TLP292(GR-TPL,E(T

Part number: TLP292

CTR rank: GR

Tape type: TPL (L direction)

[[G]]/RoHS COMPATIBLE: E (**Note 1**)

Domestic ID (Country/Region of origin: Thailand): T

Note 1: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

16.3. Tape Dimensions Specification

Tape Type	Division	Packing Amount (A unit per reel)
TPL	L direction	2500
TPR	R direction	2500

16.3.1. Orientation of Device in Relation to Direction of Feed

Device orientation in the carrier cavities as shown in the following figure.

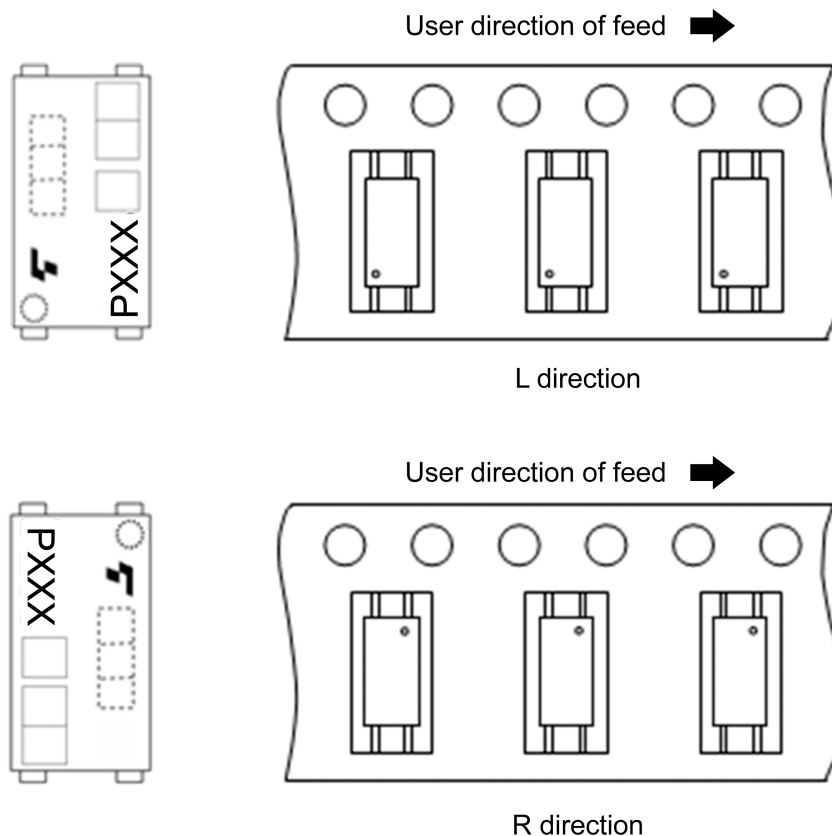


Fig. 16.3.1.1 Device Orientation

16.3.2. Empty Cavities

Characteristics	Criterion	Remarks
Occurrences of 2 or more successive empty cavities	0 device	Within any given 40-mm section of tape, not including leader and trailer
Single empty cavity	6 devices (max) per reel	Not including leader and trailer

16.3.3. Tape Leader and Trailer

The start end of the tape has 50 or more empty cavities. The hub end of the tape has 50 or more empty cavities and 2 empty turns for a cover tape.

16.3.5. Reel Specification

Material: Plastic (for protection against static electricity)

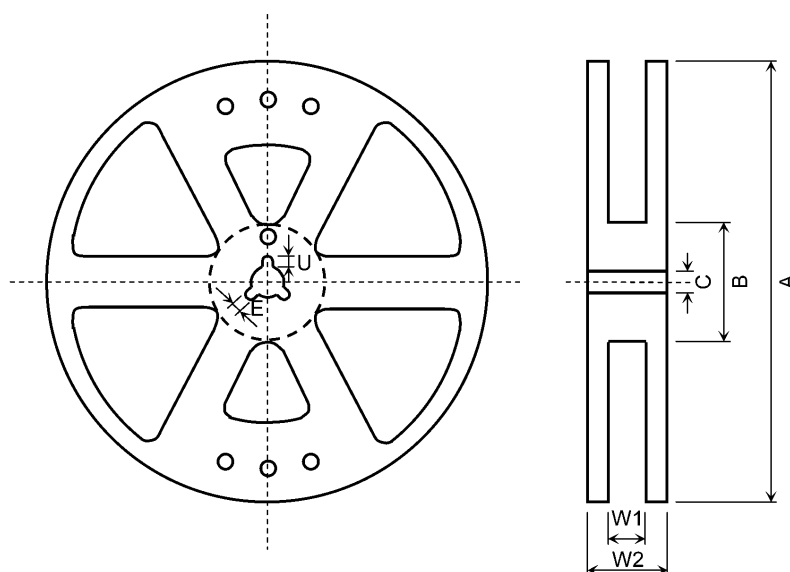
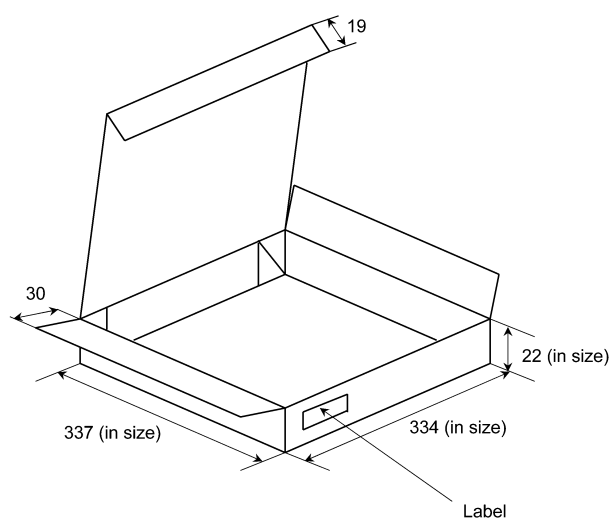


Fig. 16.3.5.1 Reel Dimensions

Table 16.3.6.1 Reel Dimensions (unit: mm)

Symbol	Dimension
A	$\phi 330 \pm 2$
B	$\phi 80 \pm 1 / \phi 100 \pm 1$
C	$\phi 13 \pm 0.5$
E	2.0 ± 0.5
U	4.0 ± 0.5
W1	13.5 ± 0.5
W2	17.5 ± 1.0

16.4. Packing (Note)



1 reel/carton (unit: mm)

Note: Taping reel diameter: $\phi 330$ mm

16.5. Label Format

- (1) Carton: The label provides the part number, quantity, lot number, the Toshiba logo, etc.
- (2) Reel: The label provides the part number, the taping name, quantity, lot number, etc.

16.6. Ordering Information

When placing an order, please specify the part number, CTR rank, tape type and quantity as shown in the following example.

Example) TLP292(GR-TPL,E(T 5000 pcs

Part number: TLP292

CTR rank: GR

Tape type: TPL (L direction)

[[G]]/RoHS COMPATIBLE: E (**Note 1**)

Domestic ID (Country/Region of origin: Thailand): T

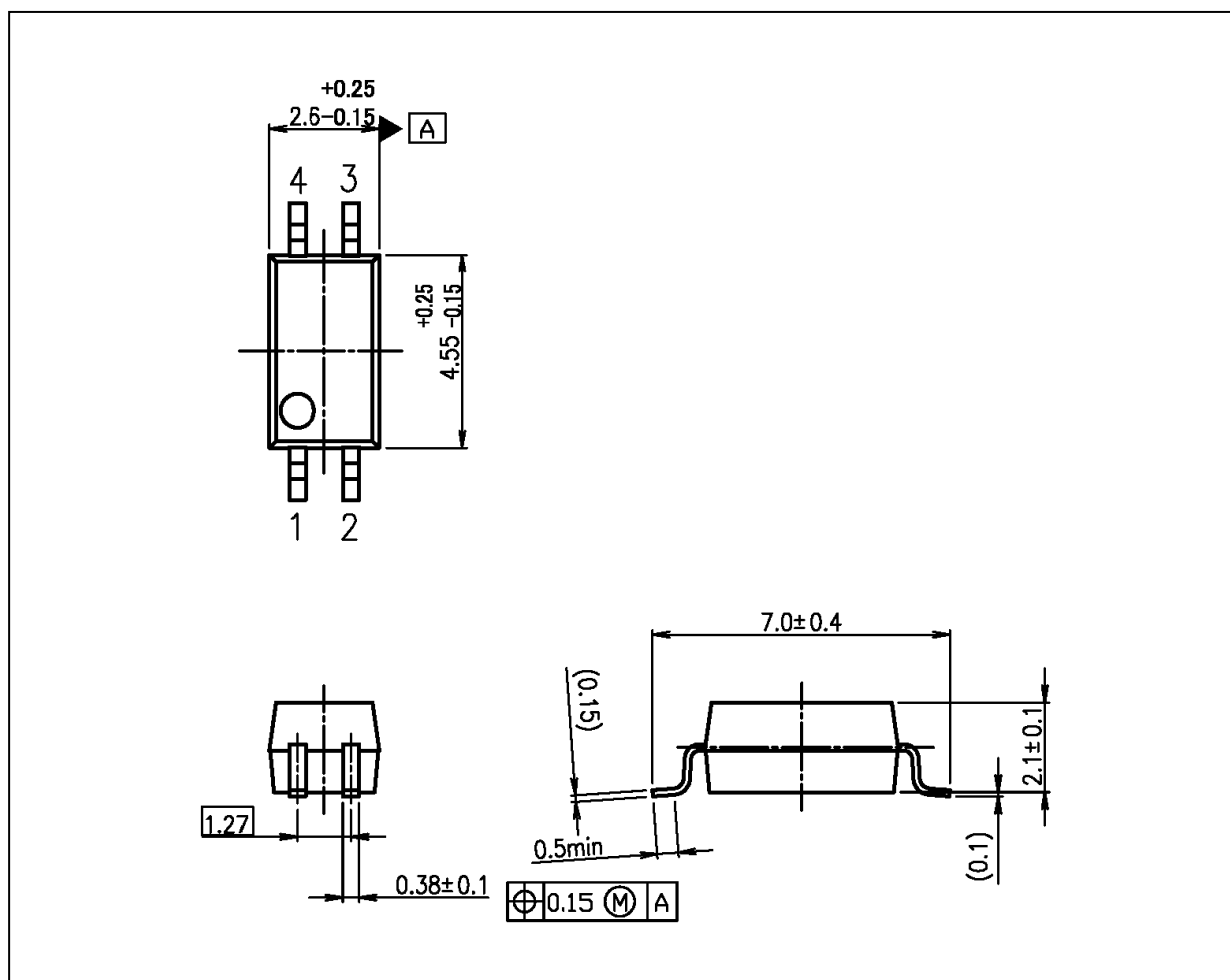
Quantity (must be a multiple of 2500): 5000 pcs

Note 1: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Package Dimensions

Unit: mm



Weight: 0.05 g (typ.)

Package Name(s)
TOSHIBA: 11-3C1

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